NSN 5961-01-346-7233

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View Online at https://aerobasegroup.com/nsn/5961-01-346-7233 **Inclosure Material:** Plastic **Overall Length:** 0.210 inches **Overall Height:** 0.205 inches **Overall Width:** 0.165 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-92 **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 30.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source **Current Rating Per Characteristic:** 30.00 nanoamperes reverse gate current with all other terminals short-circuit to source, junction-gate and 10.00 nanoamperes off-state current, dc and 5.00 milliamperes zero-gate-voltage drain current **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 27014-+1087 manufacturers standard Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0